

EPC2019 Information


For Reference Only

Part Number [EPC2019](#)
Manufacturer EPC
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description TRANS GAN 200V 8.5A BUMPED DIE
Package Die
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


EPC2019 Specifications

Manufacturer Part Number	EPC2019
Manufacturer	EPC
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	Die
Series	eGaN?
FET Type	N-Channel
Technology	GaN FET (Gallium Nitride)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	8.5A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	5V
Vgs(th) (Max) @ Id	2.5V @ 1.5mA
Gate Charge (Qg) (Max) @ Vgs	2.5nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	270pF @ 100V
Vgs (Max)	+6V, -4V
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	50 mOhm @ 7A, 5V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	Die
Package / Case	Die

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EPC2019 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2019 Payment Methods



EPC2019 Shipping Methods



If you have any question about EPC2019, please do not hesitate to contact us!

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